# NSN 5961-00-011-7020

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Inclosure Material:

Metal

**Overall Length:** 

0.219 inches

**Overall Width:** 

0.290 inches

# **Overall Diameter:**

0.375 inches

# **Mounting Facility Quantity:**

1

#### Internal Configuration:

Junction contact

#### **Mounting Method:**

Threaded stud

# Features Provided:

#### Hermetically sealed case

Thread Size:

0.164 inches

# Semiconductor Material:

Silicon

# Voltage Rating In Volts Per Characteristic:

55.0 breakdown voltage, collector-to-base, emitter open and 40.0 breakdown voltage, collector-to-emitter, base open and 3.5 breakdown voltage, emitter-to-base, collector open

# **Current Rating Per Characteristic:**

Between 500.00 milliamperes source cutoff current and 1.00 amperes source cutoff current

# **Power Rating Per Characteristic:**

10.0 watts small-signal input power, common-collector

# Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

#### **Special Features:**

Junction pattern arrangement: npn

#### **Thread Series Designator:**

Unc

#### **Terminal Type And Quantity:**

4 ribbon

#### **Specification Data:**

80131-release5388 professional/industrial association specification

#### Shelf Life:

N/a

#### Unit Of Measure:

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#### Demilitarization:

No

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